1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complements: BCW68F/G/H

2 Features and benefits

High current

AEC-Q101 qualified

3 Applications

· General-purpose switching and amplification

4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	1	Α
h _{FE}	DC current gain	V_{CE} = 1 V; I_{C} = 100 mA; T_{amb} = 25 °C	[1]				
	BCW66F			100	-	250	
	BCW66G			160	-	400	
	BCW66H			250	-	600	

[1] pulsed: $t_p \le 300 \mu s$, $\delta \le 0.02$



5 Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		
2	Е	emitter	3	C
3	С	collector		BE sym123

6 Ordering information

Table 3. Ordering information

Table of Oracinity information					
Type number	Package				
	Name	Description	Version		
BCW66F	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		
BCW66G					
BCW66H					

7 Marking

Table 4. Marking

Type number		Marking code
BCW66F	[1]	EQ%
BCW66G	[1]	ER%
BCW66H	[1]	ES%

^{[1] % =} placeholder for manufacturing site code

8 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

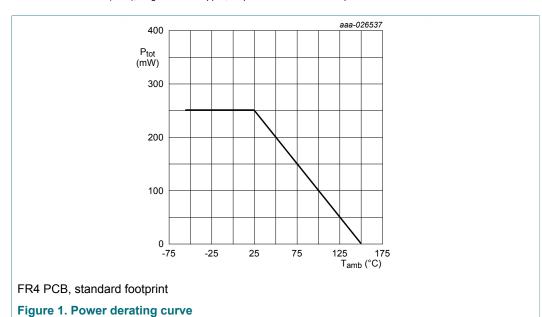
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	45	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	1	Α
I _B	base current		-	100	mA

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Symbol	Parameter	Conditions	Min	Max	Unit
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$ [1]	-	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C
T _{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided chopper, tin-plated and standard footprint.

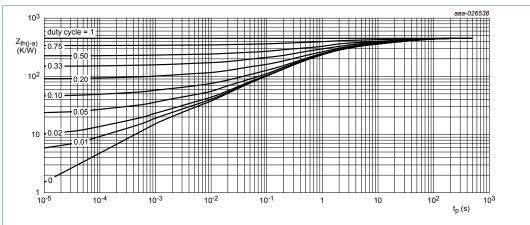


9 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air [1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

Figure 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10 Electrical characteristics

Table 7. Electrical characteristics

 T_{amb} = 25 °C unless otherwise specified.

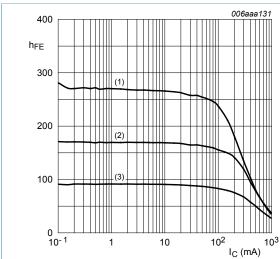
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base	V _{CB} = 40 V; I _E = 0 A		-	-	20	nA
cut-off current		$V_{CB} = 40 \text{ V}; I_{E} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A		-	-	20	nA
h _{FE}	DC current gain						
	BCW66F/G/H	V _{CE} = 1 V; I _C = 100 μA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 1 mA		75	-	-	
BCW66F	BCW66F/G/H	V _{CE} = 1 V; I _C = 10 mA		75	-	-	
	BCW66F	V _{CE} = 1 V; I _C = 100 mA	[1]	100	-	250	
	BCW66G		[1]	160	-	400	
	BCW66H		[1]	250	-	630	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 500 mA	[1]	40	-	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	350	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	450	mV
V _{BEsat}	base-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	1.25	V
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	1.25	V
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	3	_	pF

^[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$

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Table 8.



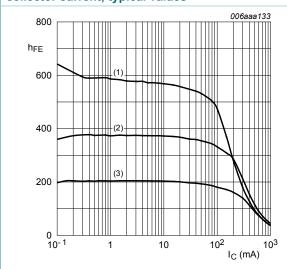
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Figure 3. BCW66F: DC current gain as a function of collector current; typical values



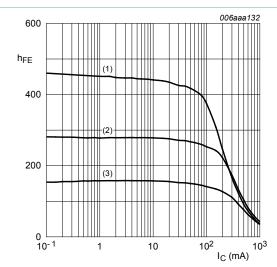
$$V_{CE} = 1 V$$

(1)
$$T_{amb}$$
 = 150 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Figure 5. BCW66H: DC current gain as a function of collector current; typical values



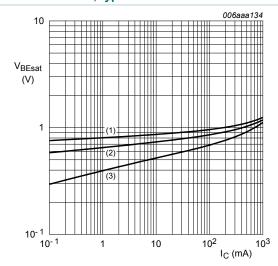
$$V_{CE} = 1 V$$

$$(1)_{amb} = 150 \, ^{\circ}C$$

(2)
$$_{amb}$$
 = 25 $^{\circ}C$

(3)
$$_{amb}$$
 = -55 $^{\circ}$ C

Figure 4. BCW66G: DC current gain as a function of collector current; typical values



$$I_C/I_B = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

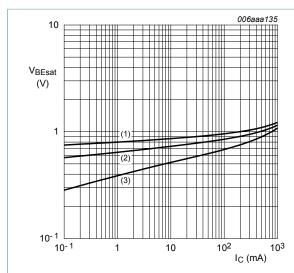
(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 6. BCW66F: Base-emitter saturation voltage as a function of collector current; typical values

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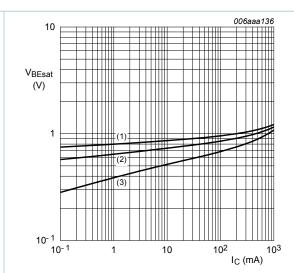


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$



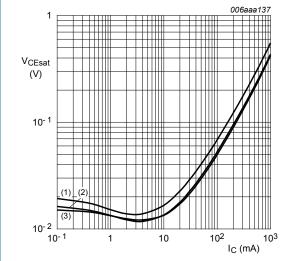
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 7. BCW66G: Base-emitter saturation voltage as a function of collector current; typical values

Figure 8. BCW66H: Base-emitter saturation voltage as a function of collector current; typical values



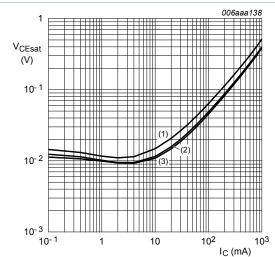
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Figure 9. BCW66F: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

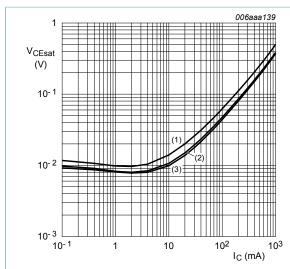
(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Figure 10. BCW66G: Collector-emitter saturation voltage as a function of collector current; typical values

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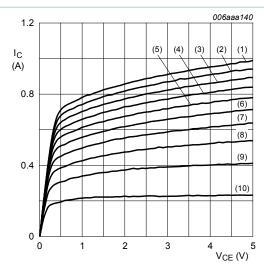
 $I_C/I_B = 10$

(1) T_{amb} = 150 °C

(2)
$$T_{amb}$$
 = 25 °C

(3) $T_{amb} = -55 \, ^{\circ}C$

Figure 11. BCW66H: Collector-emitter saturation voltage as a function of collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = 16.0 \text{ mA}$

(2) $I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$ (6) $I_B = 8.0 \text{ mA}$

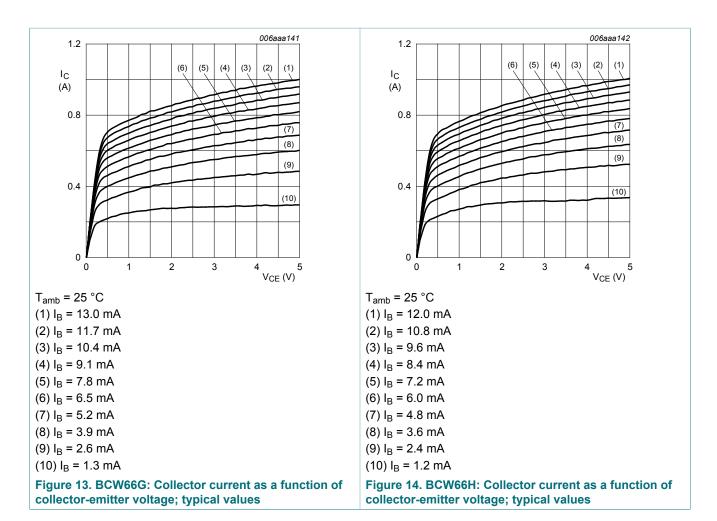
 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$

 $(10) I_B = 1.6 \text{ mA}$

Figure 12. BCW66F: Collector current as a function of collector-emitter voltage; typical values



11 Test information

11.1 Quality information

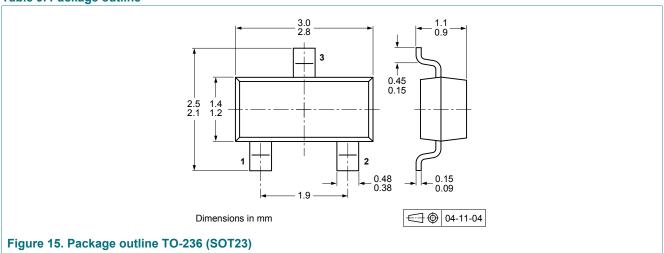
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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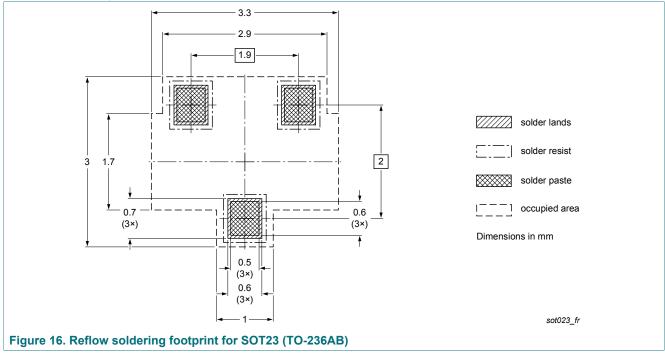
12 Package outline

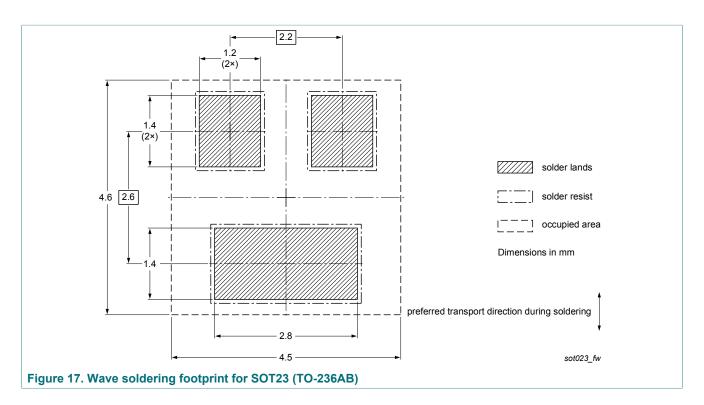
Table 9. Package outline



13 Soldering

Table 10. Soldering





14 Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCW66x_SER v.1	21 April 2017	Product data sheet	-	-

15 Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BCW66 series

45 V, 800 mA NPN general-purpose transistor

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BCW66 series

45 V, 800 mA NPN general-purpose transistor

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